

# Low Voltage Dual D-Type Positive Edge-Triggered Flip-Flop 74LVX74

# **General Description**

The LVX74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary  $(Q,\overline{Q})$  outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

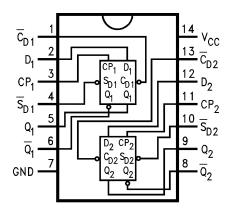
# Asynchronous Inputs:

- LOW Input to  $\overline{S}_D$  (Set) Sets Q to HIGH Level
- LOW Input to  $\overline{C}_D$  (Clear) Sets Q to LOW Level
- Clear and Set are Independent of Clock
- Simultaneous LOW on  $\overline{C}_D$  and  $\overline{S}_D$  Makes Both Q and  $\overline{Q}$  HIGH

#### **Features**

- Input Voltage Level Translation from 5 V to 3 V
- Ideal for Low Power/Low Noise 3.3 V Applications
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- Pb-Free, Halogen Free/BFR Free and RoHS Compliant

# **Connection Diagram**



#### **Pin Description**

Pin Names	Description
D <sub>1</sub> , D <sub>2</sub>	Data Inputs
CP <sub>1</sub> , CP <sub>2</sub>	Clock Pulse Inputs
$\overline{C}_{D1}, \overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}, \overline{S}_{D2}$	Direct Set Inputs
$Q_1, \overline{Q}_1, Q_2, \overline{Q}_2$	Outputs

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TSSOP-14 WB CASE 948G

## **MARKING DIAGRAM**



XXX = Specific Device Code A = Assembly Location

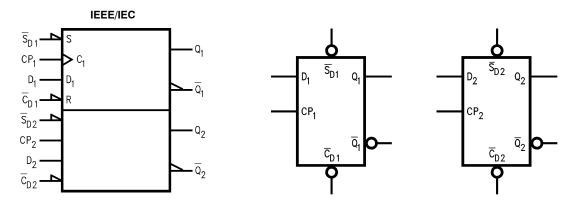
L = Wafer Lot Y = Year W = Work Week • Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 5 of this data sheet.

# **Logic Symbols**



# **Truth Table**

(Each Half)

	Inp	Out	outs		
SD	<u>C</u> D	СР	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	Х	Х	L	Н
L	L	Х	Х	Н	Н
Н	Н	~	Н	Н	L
Н	Н	~	L	L	Н
Н	Н	L	Х	$Q_0$	$\overline{Q}_0$

H = HIGH Voltage Level

L = LOW Voltage Level

 $\begin{array}{l} \text{X = Immaterial} \\ \text{$\checkmark$ = LOW-to-HIGH Clock Transition} \\ \text{$Q_0$ $(\overline{\mathbb{Q}}_0)$ = Previous Q $(\overline{\mathbb{Q}})$ before LOW-to-HIGH Transition of Clock} \\ \end{array}$ 

## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Para	meter	Rating	Unit
V <sub>CC</sub>	Supply Voltage		−0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current, $V_I = -0.5 \text{ V}$		-20	mA
V <sub>I</sub>	DC Input Voltage	DC Input Voltage		V
lok	DC Output Diode Current V <sub>O</sub> = -0.5 V		-20	mA
		$V_{O} = V_{CC} + 0.5 V$	+20	mA
V <sub>O</sub>	DC Output Voltage		-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>O</sub>	DC Output Source or Sink Current		±25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current		±50	mA
T <sub>STG</sub>	Storage Temperature		-65 to +150	°C
P <sub>D</sub>	Power Dissipation		833	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# **RECOMMENDED OPERATING CONDITIONS** (Note 1)

Symbol	Parameter	Rating	Unit
V <sub>CC</sub>	Supply Voltage	2.0 to 3.6	V
VI	Input Voltage	0 to 5.5	V
Vo	Output Voltage	0 to V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature	-40 to +85	°C
Δt / ΔV	Input Rise and Fall Time	0 to 100	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

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# DC ELECTRICAL CHARACTERISTICS

					T <sub>A</sub> = 25°C		T <sub>A</sub> = -40°	C to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input	2.0		1.5	-	-	1.5	-	V
	Voltage	3.0	1	2.0	-	-	2.0	-	
		3.6		2.4	-	-	2.4	-	
$V_{IL}$	LOW Level Input	2.0		-	-	0.5	-	0.5	V
	Voltage	3.0		_	-	8.0	-	0.8	
		3.6	1	_	-	0.8	-	0.8	
V <sub>OH</sub>	HIGH Level Output Voltage	2.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -50 \mu A$	1.9	2.0	_	1.9	_	V
		3.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -50 \mu A$	2.9	3.0	_	2.9	_	
			$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -4 \text{ mA}$	2.58	_	_	2.48	_	
V <sub>OL</sub>	LOW Level Output Voltage	2.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 50 \mu A$	-	0.0	0.1	-	0.1	٧
		3.0	$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 50 \mu A$	-	0.0	0.1	-	0.1	
			$V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 4 \text{ mA}$	-	_	0.36	-	0.44	
I <sub>IN</sub>	Input Leakage Current	3.6	V <sub>IN</sub> = 5.5 V or GND	-	-	±0.1	-	±1.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	3.6	V <sub>IN</sub> = V <sub>CC</sub> or GND	-	_	2.0	-	20.0	μΑ

# NOISE CHARACTERISTICS (Note 2)

				T <sub>A</sub> = 25°C		
Symbol	Characteristic	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Тур	Limit	Unit
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	50	0.3	0.5	V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	50	-0.3	-0.5	V
$V_{IHD}$	Minimum HIGH Level Dynamic Input Voltage	3.3	50	-	2.0	V
$V_{ILD}$	Maximum LOW Level Dynamic Input Voltage	3.3	50	-	0.8	V

<sup>2.</sup> Input  $t_r = t_f = 3.0 \text{ ns}$ 

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#### **AC ELECTRICAL CHARACTERISTICS**

				T <sub>A</sub> = 25°C T <sub>A</sub>	T <sub>A</sub> = 25°C			) to 85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay $CP_n$ to $Q_n$ or $\overline{Q}_n$	2.7	15 50	-	7.3 9.8	15.0 18.5	1.0 1.0	18.5 22.0	ns
		3.3 ± 0.3	15 50	- -	5.7 8.2	9.7 13.2	1.0 1.0	11.5 15.0	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay $\overline{C}_{Dn}$ to $\overline{S}_{Dn}$ to $\overline{Q}_{n}$ or $\overline{Q}_{n}$	2.7	15 50	- -	8.4 10.9	15.6 19.1	1.0 1.0	18.5 22.0	ns
		3.3 ± 0.3	15 50	- -	6.6 9.1	10.1 13.6	1.0 1.0	12.0 15.5	
t <sub>W</sub>	$CP_n$ or $\overline{C}_{Dn}$ or $\overline{S}_{Dn}$	2.7	-	8.5	-	-	10.0	-	ns
	Pulse Width	$3.3 \pm 0.3$	-	6.0	-	-	7.0	-	
t <sub>S</sub>	Setup Time, D <sub>n</sub> to CP <sub>n</sub>	2.7	-	8.0	-	-	9.5	-	ns
		$3.3 \pm 0.3$	-	5.5	_	-	6.5	-	
t <sub>H</sub>	Hold Time, D <sub>n</sub> to CP <sub>n</sub>	2.7	-	0.5	_	-	0.5	-	ns
		3.3 ± 0.3	-	0.5	-	-	0.5	-	
t <sub>REC</sub>	Recovery Time,	2.7	-	6.5	-	-	7.5	-	ns
	$\overline{\mathbb{C}P}_{n}$ or $\overline{\mathbb{S}}_{\mathbb{D}n}$ to $\mathbb{CP}_{n}$	$3.3 \pm 0.3$	-	5.0	-	-	5.0	-	
f <sub>MAX</sub>	Maximum Clock Frequency	2.7	15 50	55 45	135 60	_ _	50 40	- -	MHz
		3.3 ± 0.3	15 50	95 60	145 85	- -	80 50	- -	
t <sub>OSLH</sub> ,	Output to Output Skew	2.7	50	-	-	1.5	-	1.5	ns
toshl	(Note 3)	3.3		_	-	1.5	-	1.5	

<sup>3.</sup> Parameter guaranteed by design toslh = |tplhm-tplhn|, toshl = |tphlm-tphln|

# **CAPACITANCE**

		T <sub>A</sub> = 25°C			T <sub>A</sub> = -40		
Symbol	Parameter	Min	Тур	Max	Min	Max	Unit
C <sub>IN</sub>	Input Capacitance	-	4	10	-	10	pF
$C_{PD}$	Power Dissipation Capacitance (Note 4)	_	25	_	_	-	pF

<sup>4.</sup>  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} \times I_{CC}}{2 \text{ (per F/F)}}$ 

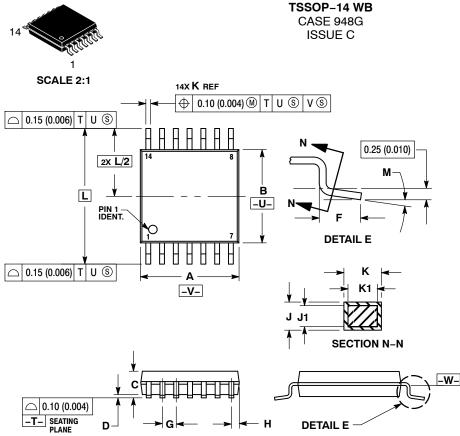
## **ORDERING INFORMATION**

Device	Package	Marking	Shipping <sup>†</sup>
74LVX74MTCX	TSSOP-14	LVX 74	2500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <a href="https://example.com/BRD8011/D">BRD8011/D</a>.

<sup>\*-</sup>Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable





**DATE 17 FEB 2016** 

- NOTES.

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

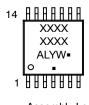
  3. DIMENSION A DOES NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
  INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

  5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

  6. TERMINAL NUMBERS ARE SHOWN FOR DEFERENCE ONLY
- REFERENCE ONLY.
  DIMENSION A AND B ARE TO BE
  DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026	BSC
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252	BSC
М	0 °	8 °	0 °	8 °

# **GENERIC MARKING DIAGRAM\***



= Assembly Location

= Wafer Lot Υ = Year

W = Work Week

= Pb-Free Package (Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

SOLDERI	NG FOOTPRINT
<	7.06
1	
	0.65 PITCH
14X 0.36	<del></del>
1.20	DIMENSIONS: MILLIMETERS

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